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## Notice of Allowability

Application No.	Applicant(s)	
10/619,125	TIHANYI, JENO	
Examiner	Art Unit	
Dang T Nguyen	2824	

Notice of Allowability	Examiner	Art Unit	
	Dang T Nguyen	2824	
The MAILING DATE of this communication appear All claims being allowable, PROSECUTION ON THE MERITS IS (0 herewith (or previously mailed), a Notice of Allowance (PTOL-85) of NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT RIG of the Office or upon petition by the applicant. See 37 CFR 1.313 a	OR REMAINS) CLOSED in this apport of the appropriate communication BHTS. This application is subject to	olication. If not include will be mailed in due	ed course. <b>THIS</b>
1. This communication is responsive to 14 December 2004.			
2. ☑ The allowed claim(s) is/are <u>1-15</u> .			
3. $igspace$ The drawings filed on <u>14 July 2003</u> are accepted by the Exa	miner.		
4. Acknowledgment is made of a claim for foreign priority und a) All b) Some* c) None of the:  1. Certified copies of the priority documents have to the priority documents have to the certified copies of the priority documents have to the certified copies of the priority documents have to the certified copies of the priority documents have to the certified copies of the priority documents have to the certified copies of the priority documents have to the certified copies of the priority documents have to the certified copies of the priority documents have to the certified copies of the priority documents have to the certified copies of the priority documents have to the certified copies of the priority documents have to the certified copies of the priority documents have to priori	peen received. peen received in Application No uments have been received in this reference in this reference in this reference in this application.  The second in Application in the a reply of this application.  The second in the attached EXAMINER's reason(s) why the oath or declarate in the submitted.  The second in the second in the control i	national stage applicational stage application and stage application of the front (not the last).	quirements OTICE OF
Attachment(s)  1. ☑ Notice of References Cited (PTO-892)  2. ☐ Notice of Draftperson's Patent Drawing Review (PTO-948)  3. ☐ Information Disclosure Statements (PTO-1449 or PTO/SB/08 Paper No./Mail Date	5. ☐ Notice of Informal P 6. ☐ Interview Summary Paper No./Mail Dat 7. ☐ Examiner's Amenda 8. ☒ Examiner's Stateme 9. ☒ Other <u>Search histor</u>	(PTO-413), re nent/Comment ent of Reasons for Allo	·

SUPERVISORY PATENT EXAMINER TECHNOLOGY CENTER 2800

## Response to Amendment

1. This office action is in response to applicant's amendment received on 12/14/2004. Claims 1 - 15 are pending on this application. Claims 1 and 6 are independent claims.

## Allowable Subject Matter

- 2. Claims 1 15 are allowed.
- 3. The following is a statement of reasons for the indication of allowable subject matter:

With regard to claim 1, the primary reason for indication of allowable subject matter is that the prior art fails to teach or suggest "the heating device having a switching device and a heating element in direct proximity with said memory material, and said switching device having a field-effect transistor with a drain region formed as a heating region".

With regard to claim 6, the primary reason for indication of allowable subject matter is that the prior art fails to teach or suggest "the heating device having a switching device and a heating element in direct proximity with said memory material, and said heating element has a diode device".

4. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure.

Leung et al. (Patent Number: 6,075,720) discloses a standard DRAM utilizes a charge storage cell for storing a data bit and having a cell access FET (field effect

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transistor) which has its gate terminal connected to a word line and its drain terminal connected to a bit line.

Klersy et al. (Patent Number: 5,933,365) discloses a thermal control means includes heating means for transferring heat energy into at least a portion of the volume of memory material. The heating means may be implemented by one or more heating layers. The heating layers are preferably thin-film structures. Preferably, at least one of the heating layers is deposited adjacent to the volume of memory material.

5. Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

## **Contact Information**

6. Any inquiry concerning this communication from the examiner should be directed to Dang Nguyen, who can be reached by telephone at (571) 272-1955. Normal contact times are M-F, 8:00 AM - 4:30 PM.

Upon an unsuccessful attempt to contact the examiner, the examiner's supervisor, Richard Elms, may be reached at (571) 272-1869.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist, whose telephone number is (703) 305-3900. The faxed phone number for organization where this application or proceeding is assigned is (703) 872-9306.

Information regarding the Status of an application may be obtained from the

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patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free) or EBC@uspto.gov.

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